

Amendments to the Specification:

Please replace the paragraph beginning at page 21, line 1, with the following amended paragraph:

The cross section through ~~[[A-A1]]~~ A-A' of the construction shown in Figure 3 corresponds to Figure 1(D). In other words, the construction shown in Figure 3 has a construction in which three thin-film transistors shown in Figure 1(D) are connected in parallel. Each transistor has a common gate electrode, and the source electrode and drain electrode are wired in common by contacts 305 and 306.